# NSN 5962-00-511-3889

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-511-3889

# **Body Length:**

Between 0.740 inches and 0.890 inches

# Body Width:

Between 0.220 inches and 0.310 inches

# **Body Height:**

Between 0.140 inches and 0.205 inches

## **Maximum Power Dissipation Rating:**

625.0 milliwatts

#### **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

### Storage Tempurature Range:

-55.0/+150.0 degrees celsius

### **Features Provided:**

Monolithic and hermetically sealed and bipolar and w/enable and w/buffered output and w/decoded output and positive outputs and

w/disable and programmed and programmable

#### **Inclosure Material:**

Ceramic and glass

# Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

5.5 volts power source

## **Time Rating Per Chacteristic:**

80.00 nanoseconds propagation delay time, low to high level output

### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

---

## Demilitarization:

Yes - demil/mli

### Fiig:

A458a0